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Little Star® 1 W Power SMD LED White





DESCRIPTION

The VLMW712U2U3XV, VLMW712T3U3US, and VLMW712T3QN rank among the most robust and light efficient LEDs in the market. Using recent and reliable nitride phosphor technology, the color stability has been improved. With its extremely high level of brightness and the package height profile, which is only 1.5 mm, the Little Star is highly suitable for both, conventional lighting and specialized application such as signal lights, traffic lights, channel lights, tube lights and garden lights among others.

PRODUCT GROUP AND PACKAGE DATA

Product group: LED
Package: SMD Little Star
Product series: power
Angle of half intensity: ± 60°

FEATURES

- · Super high brightness surface mount LED
- High flux output; up to 113 lm
- 120° viewing angle
- Compact package outline (L x W x H) in mm: 6.0 x 6.0 x 1.5



- Ultra low height profile 1.5 mm
- Designed for high current drive; up to 350 mA
- Low thermal resistance; R_{th,JP} = 10 K/W
- · Qualified according to JEDEC moisture sensitivity level 2a
- · Compatible with IR reflow soldering
- Little Star[®] are class 1M LED products. Do not view directly with optical instrument
- ESD-withstand voltage: up to 2 kV according to JESD22-A114-B
- Material categorization: For definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

- · Communication: flashLED
- Industry: white goods (e.g.: oven, microwave, etc.)
- Lighting: garden light, architecture lighting, general lighting, etc.

PARTS TABLE												
PART	COLOR	LUN	INOUS F (mlm)	LUX	at I _F	СО	ORDINA (x, y)	ATE		ORWAF OLTAG (V)		TECHNOLOGY
		MIN.	TYP.	MAX.	(mA)	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
VLMW712U2U3XV-GS08	Cool white	87 400	100 000	113 600	350	-	0.33, 0.33	-	3	3.5	4	InGaN
VLMW712T3U3US-GS08	Natural white	76 500	90 000	113 600	350	-	0.37, 0.38	-	3	3.5	4	InGaN
VLMW712T2T3QN-GS08	Warm white	67 200	75 000	87 400	350	-	0.44, 0.41	_	3	3.5	4	InGaN

ABSOLUTE MAXIMUM RATII VLMW712U2U3XV, VLMW71			d)	
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Forward current		IF	350	mA
Power dissipation		P _{tot}	1.4	W
Junction temperature		T _j	+ 120	°C
Surge current t < 10 µs, d = 0.1		I _{FM}	1000	mA
Operating temperature range		T _{amb}	- 40 to + 100	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Thermal resistance junction/pin		R _{thJP}	10	K/W

Note

• Not designed for reverse operation



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OPTICAL AND ELECTRICAL CHAVENUT OF THE PROPERTY OF THE PROPERT		_{lmb} = 25 °C, ι	unless oth	erwise sp	ecified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 350 mA	ф	87 400	100 000	113 600	mlm
Luminous intensity	IF = 330 IIIA	l _V	-	33 500	-	mcd
Chromaticity coordinate x acc. to CIE 1931	I _F = 350 mA	х	-	0.33	-	
Chromaticity coordinate y acc. to CIE 1931	$I_F = 350 \text{ mA}$	у	-	0.33	-	
Angle of half intensity	I _F = 350 mA	φ	-	± 60	-	deg
Forward voltage (1)	I _F = 350 mA	V _F	3	3.5	4	V
Temperature coefficient of V _F	I _F = 350 mA	TC _{VF}	-	- 3	-	mV/K
Temperature coefficient of I _V	$I_F = 350 \text{ mA}$	TC _{IV}	-	- 0.4	-	%/K

Note

 $^{^{(1)}}$ Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of $\pm~0.05~\text{V}$

OPTICAL AND ELECTRICAL CH VLMW712T3U3US, NATURAL W	•	_{mb} = 25 °C, ι	unless oth	erwise sp	ecified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 350 mA	ф	76 500	90 000	113 600	mlm
Luminous intensity	IF = 330 IIIA	I _V	-	29 700	-	mcd
Chromaticity coordinate x acc. to CIE 1931	$I_F = 350 \text{ mA}$	х	-	0.37	-	
Chromaticity coordinate y acc. to CIE 1931	$I_F = 350 \text{ mA}$	у	-	0.38	-	
Angle of half intensity	$I_F = 350 \text{ mA}$	φ	-	± 60	-	deg
Forward voltage (1)	$I_F = 350 \text{ mA}$	V _F	3	3.5	4	V
Temperature coefficient of V _F	I _F = 350 mA	TC _{VF}	-	- 3	-	mV/K
Temperature coefficient of I _V	$I_F = 350 \text{ mA}$	TC _{IV}	-	- 0.4	-	%/K

Note

 $^{^{(1)}}$ Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of \pm 0.05 V

OPTICAL AND ELECTRICAL CHA VLMW712T2T3QN, WARM WHIT		_{amb} = 25 °C, I	unless oth	erwise sp	ecified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _E = 350 mA	ф	67 200	75 000	87 400	mlm
Luminous intensity	I _F = 350 MA	l _V	-	25 000	-	mcd
Chromaticity coordinate x acc. to CIE 1931	I _F = 350 mA	х	-	0.44	-	
Chromaticity coordinate y acc. to CIE 1931	$I_F = 350 \text{ mA}$	у	_	0.41	-	
Angle of half intensity	I _F = 350 mA	φ	-	± 60	-	deg
Forward voltage (1)	I _F = 350 mA	V _F	3	3.5	4	V
Temperature coefficient of V _F	$I_F = 350 \text{ mA}$	TC _{VF}	-	- 3	-	mV/K
Temperature coefficient of I _V	I _F = 350 mA	TC _{IV}	-	- 0.4	-	%/K

Note

 $^{^{(1)}}$ Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of \pm 0.05 V



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LUMINOUS INTENSITY/FLUX C	LUMINOUS INTENSITY/FLUX CLASSIFICATION		
GROUP	LUMINOUS FLUX Φ _V (mlr	n) CORRELATION TABLE	
STANDARD	MIN.	MAX.	
T2	67 200	76 500	
T3	76 500	87 400	
U2	87 400	99 400	
U3	99 400	113 600	

Note

• Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %. The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel). In order to ensure availability, single brightness groups will not be orderable. In a similar manner for colors where color groups are measured and binned, single color groups will be shipped in any one reel. In order to ensure availability, single color groups will not be orderable.

CHROMATICITY COORDINATED GROUPS FOR COOL WHITE SMD LED			
BIN	Сх	Су	
	0.301	0.342	
	0.314	0.353	
XM	0.315	0.343	
	0.303	0.333	
	0.301	0.342	
	0.303	0.333	
	0.315	0.343	
XN	0.316	0.332	
	0.305	0.322	
	0.303	0.333	
	0.305	0.322	
	0.316	0.332	
XO	0.318	0.319	
	0.308	0.311	
	0.305	0.322	
	0.308	0.311	
	0.318	0.319	
XP	0.32	0.301	
	0.311	0.293	
	0.308	0.311	
	0.314	0.353	
	0.329	0.366	
WM	0.329	0.354	
	0.315	0.343	
	0.314	0.353	
	0.315	0.343	
	0.329	0.354	
WN	0.329	0.343	
	0.316	0.332	
	0.315	0.343	
	0.316	0.332	
	0.329	0.343	
WO	0.329	0.33	
	0.318	0.319	
	0.316	0.332	
	0.318	0.319	
	0.329	0.33	
WP	0.329	0.319	
	0.319	0.31	
	0.318	0.319	



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CHROMATICITY COORDINATED GROUPS FOR COOL WHITE SMD LED			
BIN	Сх	Су	
	0.319	0.31	
	0.329	0.319	
WQ	0.33	0.311	
	0.32	0.301	
	0.319	0.31	
	0.329	0.366	
	0.348	0.383	
VM	0.347	0.368	
	0.329	0.354	
	0.329	0.366	
	0.329	0.354	
	0.347	0.368	
VN	0.346	0.357	
	0.329	0.343	
	0.329	0.354	
	0.329	0.343	
	0.346	0.357	
VO	0.344	0.343	
	0.329	0.33	
	0.329	0.343	
	0.329	0.33	
	0.344	0.343	
VP	0.343	0.331	
	0.329	0.319	
	0.329	0.33	

Note

• Chromaticity coordinate groups are tested at a current pulse duration of 25 ms and a tolerance of ± 0.01.

ROMATICITY COORDINATED GROUPS FOR NATURAL WHITE SMD LED			
BIN	Сх	Су	
	0.348	0.383	
UM	0.367	0.4	
OW	0.364	0.383	
	0.347	0.368	
	0.347	0.368	
UN	0.364	0.383	
ON	0.362	0.372	
	0.346	0.357	
	0.346	0.357	
UO	0.362	0.372	
00	0.359	0.356	
	0.344	0.343	
	0.344	0.343	
UP	0.359	0.356	
OP	0.357	0.343	
	0.343	0.331	
	0.367	0.4	
TN 4	0.364	0.383	
TM	0.381	0.394	
	0.386	0.411	



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BIN	Сх	Су
	0.364	0.383
TNI	0.362	0.372
TN	0.378	0.381
	0.381	0.394
	0.362	0.372
ТО	0.359	0.356
10	0.374	0.365
	0.378	0.381
	0.359	0.356
TP	0.357	0.343
IP	0.37	0.351
	0.374	0.365
	0.386	0.411
SM	0.381	0.394
SIVI	0.396	0.404
	0.402	0.421
	0.381	0.394
SN	0.378	0.381
SIN	0.392	0.389
	0.396	0.404
	0.378	0.381
80	0.374	0.365
so	0.387	0.373
	0.392	0.389
	0.374	0.365
SP	0.37	0.351
24	0.382	0.358
	0.387	0.373

Note

• Chromaticity coordinate groups are tested at a current pulse duration of 25 ms and a tolerance of ± 0.01.

CHROMATICITY COORDINAT	TED GROUPS FOR WARM WHITE SM	D LED
BIN	Сх	Су
	0.421	0.433
	0.437	0.438
QM	0.43	0.421
	0.415	0.416
	0.421	0.433
	0.415	0.416
	0.43	0.421
QN	0.423	0.405
	0.409	0.4
	0.415	0.416
	0.409	0.4
	0.423	0.405
QO	0.416	0.387
	0.402	0.382
	0.409	0.4



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BIN	Сх	Су
2111	0.402	0.382
QP	0.416	0.387
QP	0.409	0.372
	0.397	0.367
	0.402	0.382
	0.437	0.438
	0.452	0.443
PM	0.444	0.426
	0.43	0.421
	0.437	0.438
	0.43	0.421
	0.444	0.426
PN	0.436	0.409
	0.423	0.405
	0.43	0.421
	0.423	0.405
	0.436	0.409
PO	0.428	0.392
	0.416	0.387
	0.423	0.405
	0.416	0.387
	0.428	0.392
PP	0.421	0.377
• •	0.409	0.372
	0.416	0.387
	0.452	0.443
	0.469	0.448
NM	0.46	0.431
INIVI	0.444	0.426
	0.444	0.443
	0.442	0.426
NINI	0.46	0.431
NN	0.451	0.414
	0.436	0.409
	0.444	0.426
	0.436	0.409
	0.451	0.414
NO	0.443	0.397
	0.428	0.392
	0.436	0.409
	0.428	0.392
	0.443	0.397
NP	0.435	0.382
	0.421	0.377
	0.428	0.392

Note

• Chromaticity coordinate groups are tested at a current pulse duration of 25 ms and a tolerance of \pm 0.01.

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

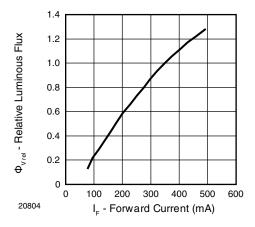


Fig. 1 - Relative Luminous Flux vs. Forward Current

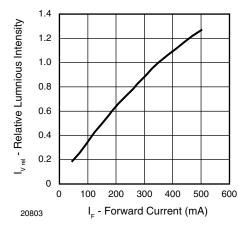


Fig. 2 - Relative Luminous Intensity vs. Forward Current

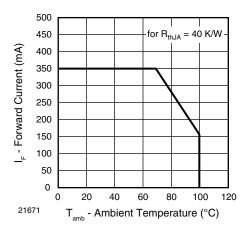


Fig. 3 - Forward Current vs. Solder Point Temperature

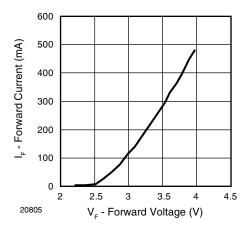


Fig. 4 - Forward Current vs. Forward Voltage

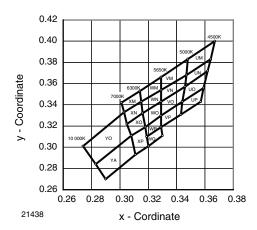


Fig. 5 - Coordinates of Color Groups for Cool White

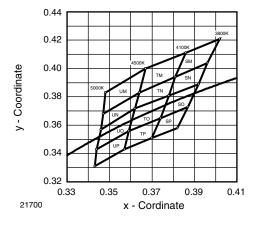


Fig. 6 - Coordinates of Color Groups for Natural White

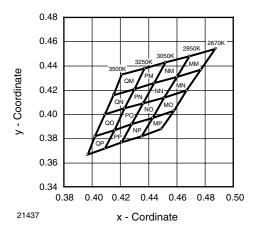


Fig. 7 - Coordinates of Color Groups for Warm White

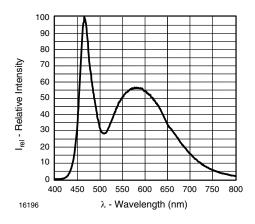


Fig. 8 - Relative Spectrale Emission for Cool White

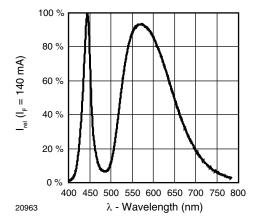


Fig. 9 - Relative Spectrale Emission for Natural White

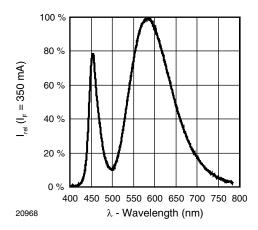


Fig. 10 - Relative Spectrale Emission for Warm White

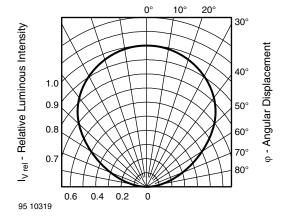
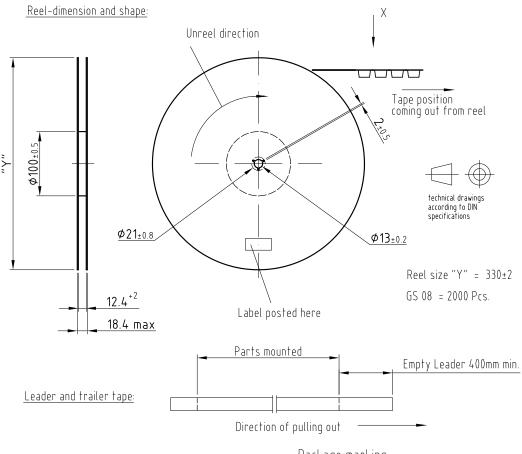


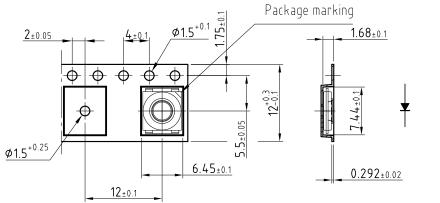
Fig. 11 - Relative Luminous Intensity vs. Angular Displacement

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TAPING DIMENSIONS in millimeters





Drawing-No.: 9.800-5094.01-4

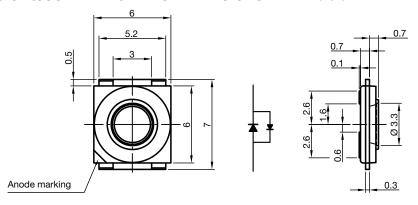
Issue: 3; 22.01.08

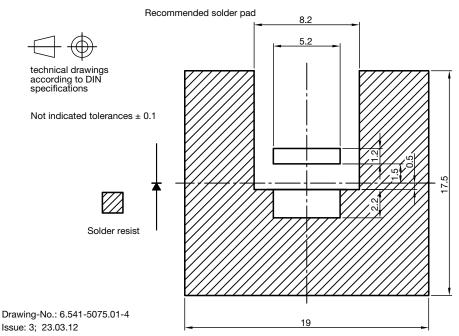
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PACKAGE DIMENSIONS/SOLDERING PADS DIMENSIONS in millimeters

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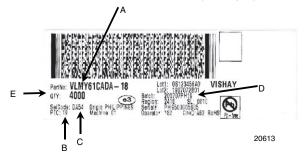


SOLDERING PROFILE

IR Reflow Soldering Profile for Lead (Pb)-free Soldering Preconditioning acc. to JEDEC level 2a 300 max. 260 °C -255 °C -240 °C 250 245 °C -217 °C Temperature (°C) 200 max 30 s 150 100 max. ramp down 6 °C/s 50 max. ramp up 3 °C/s 50 100 150 200 250 Time (s) 19885 max. 2 cycles allowed

Fig. 12 - Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020C)

BAR CODE PRODUCT LABEL (example)



- A. Type of component
- B. Manufacturing plant
- C. SEL selection code (bin):
 - e.g.: DA = code for luminous intensity group 5 = code for color group
- D. Batch no.

20070 = year 2007, week 07 PH19 = plant code

E. Total quantity

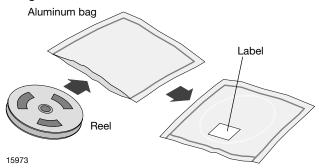


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DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

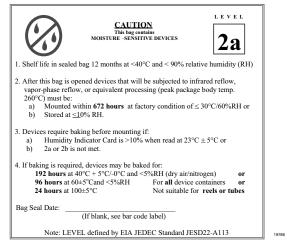
After more than 672 h under these conditions moisture content will be too high for reflow soldering.

In case of moisture absorption, the devices will recover to the former condition by drying under the following condition: 192 h at 40 $^{\circ}$ C + 5 $^{\circ}$ C/- 0 $^{\circ}$ C and < 5 $^{\circ}$ RH (dry air/nitrogen) or

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

ESD PRECATION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



Legal Disclaimer Notice

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Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

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